Title: SEMICONDUCTOR LASER MANUFACT INC HOD AND SEMICONDUCTOR LASER

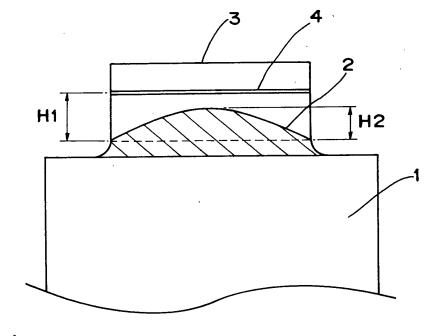
First Inventor: Tetsuyoshi INOUE

Application No.: NEW Docket No.: 204552021700

Morrison & Foerster LLP 2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888

(202) 887-1500 Sheet 1 of 7

Fig.1



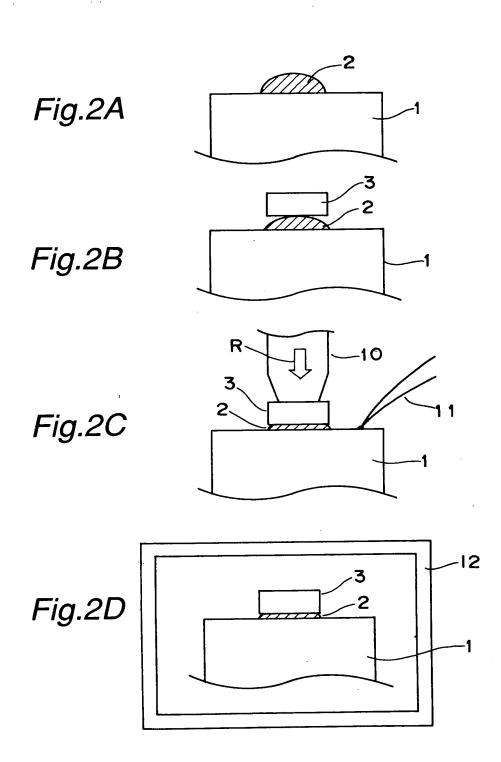
Short Title: SEMICONDUCTOR LASER MANUFACTURING MODD AND SEMICONDUCTOR LASER

First eventor: Tetsuyoshi INOUE

Application No.: NEW Docket No.: 204552021700

Morrison & Foerster LLP 2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888 (202) 887-1500

Sheet 2 of 7



Fil. ventor: Tetsuyoshi INOUE

Application No.: NEW Docket No.: 204552021700

Morrison & Foerster LLP 2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888 (202) 887-1500

Sheet 3 of 7

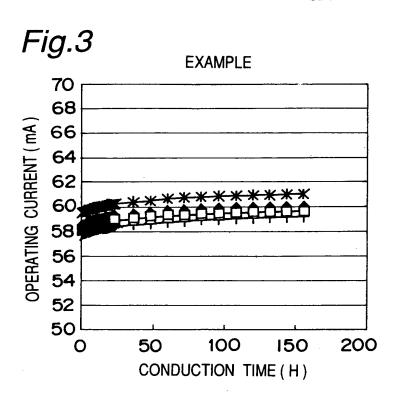
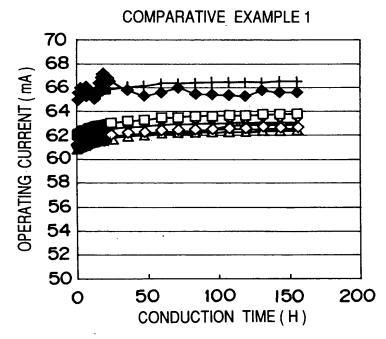


Fig.4



Short Title: SEMICONDUCTOR LASER MANUFACTURING ME D AND SEMICONDUCTOR LASER

irs. entor: Tetsuyoshi INOUE

Application No.: NEW Docket No.: 204552021700

Morrison & Foerster LLP 2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888 (202) 887-1500

Sheet 4 of 7

Fig.5

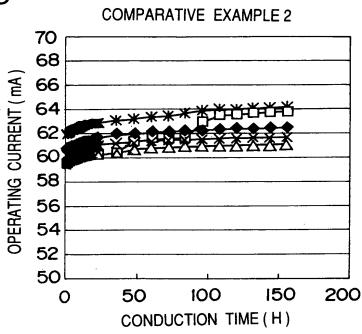
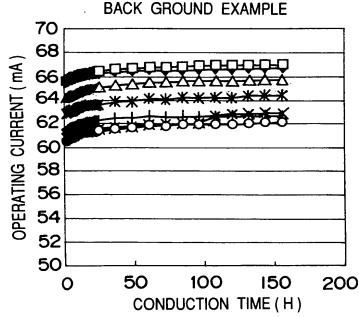


Fig.6



PATPROVED O.G. FIG.
BY CLASS GUBOLAGO
DEAFTSMAN

Short Title: SEMICONDUCTOR LASER MANUFACTURING
MIDDO AND SEMICONDUCTOR LASER

Fir. ventor: Tetsuyoshi INOUE

Application No.: NEW Docket No.: 204552021700

Morrison & Foerster LLP 2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888

(202) 887-1500

Sheet 5 of 7

Fig.7 BACK GROUND ART

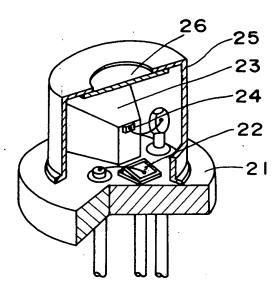
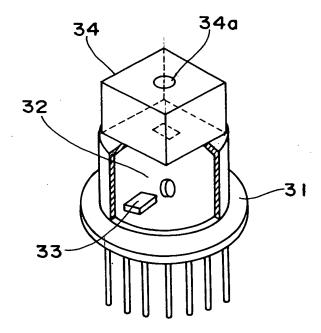


Fig.8 BACK GROUND ART



First handtor: Tetsuyoshi INOUE

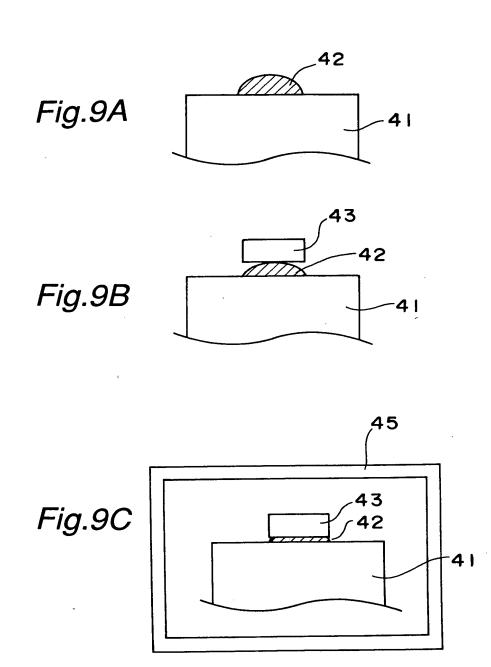
Application No.: NEW Docket No.: 204552021700

Morrison & Foerster LLP

2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888

(202) 887-1500

Sheet 6 of 7



DWWW.TC.t.t.BOI

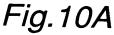
Short Title: SEMICONDUCTOR LASER MANUFACTURING ETHOD AND SEMICONDUCTOR LASER

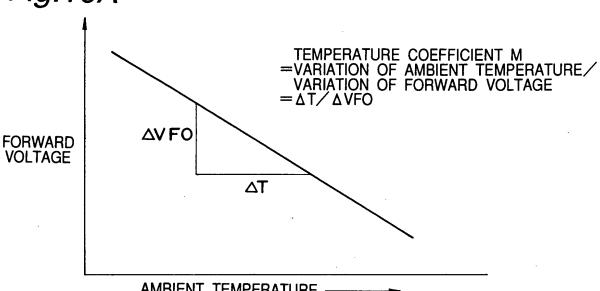
rst Inventor: Tetsuyoshi INOUE

Application No.: NEW Docket No.: 204552021700

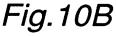
Morrison & Foerster LLP 2000 Pennsylvania Avenue, N.W. Washington, D.C. 20006-1888 (202) 887-1500

Sheet 7 of 7





AMBIENT TEMPERATURE



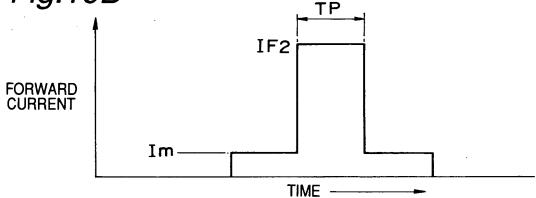


Fig.10C

